Kevin L Jensen

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The third column is the impact factor (IF) of the journal, and the fourth column is the number of citations of the article.

156
papers

3,261
citations

h-index

47
g-index

195
ext. papers

2.4
avg, IF

L-index

#	Paper	IF	Citations
156	Lattice Weyl-Wigner formulation of exact many-body quantum-transport theory and applications to novel solid-state quantum-based devices. <i>Physical Review B</i> , 1990 , 42, 9429-9457	3.3	151
155	Electron emission theory and its application: Fowler Nordheim equation and beyond. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 2003 , 21, 1528		131
154	Numerical simulation of intrinsic bistability and high-frequency current oscillations in resonant tunneling structures. <i>Physical Review Letters</i> , 1991 , 66, 1078-1081	7.4	128
153	Field emitter arrays for plasma and microwave source applications. <i>Physics of Plasmas</i> , 1999 , 6, 2241-2	2521	107
152	General formulation of thermal, field, and photoinduced electron emission. <i>Journal of Applied Physics</i> , 2007 , 102, 024911	2.5	90
151	An analytical solution for microtip field emission current and effective emission area. <i>Journal of Applied Physics</i> , 2002 , 91, 9379-9384	2.5	82
150	Perpendicular magnetic anisotropy and high spin-polarization ratio in epitaxial Fe-N thin films. <i>Physical Review B</i> , 2011 , 84,	3.3	65
149	Numerical simulation of field emission and tunneling: A comparison of the Wigner function and transmission coefficient approaches. <i>Journal of Applied Physics</i> , 1993 , 73, 4409-4427	2.5	60
148	Electron emission contributions to dark current and its relation to microscopic field enhancement and heating in accelerator structures. <i>Physical Review Special Topics: Accelerators and Beams</i> , 2008 , 11,		57
147	Emittance, surface structure, and electron emission. <i>Physical Review Special Topics: Accelerators and Beams</i> , 2014 , 17,		54
146	Space charge effects in field emission: One dimensional theory. <i>Journal of Applied Physics</i> , 2010 , 107, 014904	2.5	52
145	Exchange-correlation, dipole, and image charge potentials for electron sources: Temperature and field variation of the barrier height. <i>Journal of Applied Physics</i> , 1999 , 85, 2667-2680	2.5	52
144	Photoemission from metals and cesiated surfaces. <i>Journal of Applied Physics</i> , 2007 , 102, 074902	2.5	51
143	. IEEE Transactions on Electron Devices, 1991 , 38, 2337-2347	2.9	51
142	General thermal-field emission equation. <i>Applied Physics Letters</i> , 2006 , 88, 154105	3.4	48
141	Shielding in ungated field emitter arrays. <i>Applied Physics Letters</i> , 2015 , 106, 201603	3.4	46
140	A photoemission model for low work function coated metal surfaces and its experimental validation. <i>Journal of Applied Physics</i> , 2006 , 99, 124905	2.5	46

139	Emittance of a field emission electron source. Journal of Applied Physics, 2010, 107, 014903	2.5	45	
138	New results in the theory of Fowler-Nordheim plots and the modelling of hemi-ellipsoidal emitters. <i>Ultramicroscopy</i> , 2001 , 89, 17-22	3.1	44	
137	Simulation of resonant tunneling structures: Origin of the IV hysteresis and plateau-like structure. <i>Journal of Applied Physics</i> , 2000 , 87, 1337-1349	2.5	44	
136	Numerical calculation of particle trajectories and tunneling times for resonant tunneling barrier structures. <i>Applied Physics Letters</i> , 1989 , 55, 669-671	3.4	43	
135	The effects of scattering on current-voltage characteristics, transient response, and particle trajectories in the numerical simulation of resonant tunneling diodes. <i>Journal of Applied Physics</i> , 1990 , 67, 7602-7607	2.5	42	
134	Space charge effects in field emission: Three dimensional theory. <i>Journal of Applied Physics</i> , 2010 , 107, 014905	2.5	41	
133	Modelling field emitter arrays using line charge distributions. <i>Journal Physics D: Applied Physics</i> , 2015 , 48, 385203	3	38	
132	Graded electron affinity electron source. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 1996 , 14, 2072		38	
131	Electron emission from a single spindt-type field emitter: Comparison of theory with experiment. <i>Applied Surface Science</i> , 1997 , 111, 204-212	6.7	38	
130	Numerical simulation of transient response and resonant-tunneling characteristics of double-barrier semiconductor structures as a function of experimental parameters. <i>Journal of Applied Physics</i> , 1989 , 65, 5248-5250	2.5	38	
129	Discrete space charge affected field emission: Flat and hemisphere emitters. <i>Journal of Applied Physics</i> , 2015 , 117, 194902	2.5	37	
128	Field emitter array development for high frequency applications. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 1998 , 16, 749		37	
127	Dependence of optimal spacing on applied field in ungated field emitter arrays. <i>AIP Advances</i> , 2015 , 5, 087182	1.5	35	
126	Space charge effects on the current-voltage characteristics of gated field emitter arrays. <i>Journal of Applied Physics</i> , 1997 , 82, 845-854	2.5	35	
125	A tutorial on electron sources. <i>IEEE Transactions on Plasma Science</i> , 2018 , 46, 1881-1899	1.3	34	
124	Theory of photoemission from cesium antimonide using an alpha-semiconductor model. <i>Journal of Applied Physics</i> , 2008 , 104, 044907	2.5	34	
123	Analytical and seminumerical models for gated field emitter arrays. I. Theory. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 1996 , 14, 1942		31	
122	Generalized electron emission model for field, thermal, and photoemission. <i>Applied Physics Letters</i> , 2002 , 81, 3867-3869	3.4	31	

121	Numerical aspects on the simulation of I-V characteristics and switching times of resonant tunneling diodes. <i>Journal of Applied Physics</i> , 1990 , 67, 2153-2155	2.5	31
120	Practical considerations in the modeling of field emitter arrays with line charge distributions. Journal of Applied Physics, 2017 , 121, 203303	2.5	30
119	Effective field enhancement factor and the influence of emitted space charge. <i>Journal of Applied Physics</i> , 2015 , 118, 083302	2.5	27
118	Numerical simulation of field emission from silicon. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 1993 , 11, 371		27
117	Perspectives on Designer Photocathodes for X-ray Free-Electron Lasers: Influencing Emission Properties with Heterostructures and Nanoengineered Electronic States. <i>Physical Review Applied</i> , 2018 , 10,	4.3	27
116	A reformulated general thermal-field emission equation. <i>Journal of Applied Physics</i> , 2019 , 126, 065302	2.5	26
115	Space charge and quantum effects on electron emission. <i>Journal of Applied Physics</i> , 2012 , 111, 054917	2.5	26
114	Field emission characteristics of a small number of carbon fiber emitters. <i>AIP Advances</i> , 2016 , 6, 095007	1.5	26
113	Improved Fowler Mordheim equation for field emission from semiconductors. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 1995 , 13, 516		25
112	Heating of microprotrusions in accelerating structures. <i>Physical Review Special Topics: Accelerators and Beams</i> , 2013 , 16,		24
111			24
	Schottky conjecture, field emitters, and the point charge model. AIP Advances, 2016, 6, 065005	1.5	
110	Schottky conjecture, field emitters, and the point charge model. AIP Advances, 2016, 6, 065005 A quantum dipole choified work function for a simplified electron emission barrier. Journal of Applied Physics, 2012, 111, 054916	2.5	23
110	A quantum dipoleThodified work function for a simplified electron emission barrier. <i>Journal of</i>		23
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109	A quantum dipolehodified work function for a simplified electron emission barrier. <i>Journal of Applied Physics</i> , 2012 , 111, 054916 Time dependent models of field-assisted photoemission. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 2005 , 23, 621 The quantum efficiency of dispenser photocathodes: Comparison of theory to experiment. <i>Applied Physics Letters</i> , 2004 , 85, 5448-5450 Migration and escape of barium atoms in a thermionic cathode. <i>IEEE Transactions on Plasma Science</i> ,	2.5	23
109 108 107	A quantum dipolehodified work function for a simplified electron emission barrier. <i>Journal of Applied Physics</i> , 2012 , 111, 054916 Time dependent models of field-assisted photoemission. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 2005 , 23, 621 The quantum efficiency of dispenser photocathodes: Comparison of theory to experiment. <i>Applied Physics Letters</i> , 2004 , 85, 5448-5450 Migration and escape of barium atoms in a thermionic cathode. <i>IEEE Transactions on Plasma Science</i> , 2000 , 28, 772-781 Emitter quantization and double hysteresis in resonant-tunneling structures: A nonlinear model of charge oscillation and current bistability. <i>Physical Review B</i> , 2000 , 61, 5644-5665 Operation and optimization of gated field emission arrays in inductive output amplifiers. <i>IEEE</i>	2.5 3.4 1.3	23 22 22

103	Photon assisted field emission from a silicon emitter. Solid-State Electronics, 2001, 45, 831-840	1.7	21
102	Theory of Field Emission33-104		21
101	INTRINSIC HIGH-FREQUENCY OSCILLATIONS AND EQUIVALENT CIRCUIT MODEL IN THE NEGATIVE DIFFERENTIAL RESISTANCE REGION OF RESONANT TUNNELING DEVICES. COMPEL - the International Journal for Computation and Mathematics in Electrical and Electronic Engineering, 1991,	0.7	21
100	10, 241-253 Control of bulk and edge screening effects in two-dimensional arrays of ungated field emitters. Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics, 2016, 34, 041215	1.3	21
99	Measurement and analysis of thermal photoemission from a dispenser cathode. <i>Physical Review Special Topics: Accelerators and Beams</i> , 2003 , 6,		20
98	Quantum entangled supercorrelated states in the Jaynes (Iummings model. <i>Physics Letters, Section A: General, Atomic and Solid State Physics</i> , 1999 , 259, 285-290	2.3	20
97	Application of a general electron emission equation to surface nonuniformity and current density variation. <i>Journal of Vacuum Science & Technology B</i> , 2008 , 26, 831		19
96	Prototype dispenser photocathode: Demonstration and comparison to theory. <i>Applied Physics Letters</i> , 2007 , 90, 114108	3.4	19
95	Analysis of a photon assisted field emission device. <i>Applied Physics Letters</i> , 2000 , 77, 585-587	3.4	19
94	An analytical model of an emission-gated Twystrode using a field emitter array. <i>Journal of Applied Physics</i> , 1998 , 83, 7982-7992	2.5	19
93	Edge enhancement control in linear arrays of ungated field emitters. <i>Journal of Applied Physics</i> , 2016 , 119, 043301	2.5	19
92	On the application of quantum transport theory to electron sources. <i>Ultramicroscopy</i> , 2003 , 95, 29-48	3.1	18
91	Emission statistics and the characterization of array current. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 2003 , 21, 412		17
90	Active bialkali photocathodes on free-standing graphene substrates. <i>Npj 2D Materials and Applications</i> , 2017 , 1,	8.8	16
89	2D/3D image charge for modeling field emission. <i>Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics</i> , 2017 , 35, 02C101	1.3	16
88	Thermal-field and photoemission from meso- and micro-scale features: Effects of screening and roughness on characterization and simulation. <i>Journal of Applied Physics</i> , 2019 , 125, 234303	2.5	16
87	Current from a nano-gap hyperbolic diode using shape-factors: Theory. <i>Journal of Applied Physics</i> , 2017 , 122, 064501	2.5	16
86	Single layer graphene protective gas barrier for copper photocathodes. <i>Applied Physics Letters</i> , 2017 , 110, 041607	3.4	15

85	Field Emission (Fundamental Theory to Usage 2014 , 1-29		15
84	Bunch characteristics of an electron beam generated by a diamond secondary emitter amplifier. <i>Journal of Applied Physics</i> , 2010 , 108, 044509	2.5	15
83	Factors affecting performance of dispenser photocathodes. <i>Journal of Applied Physics</i> , 2007 , 102, 1049	9 01 .5	15
82	Analytic expressions for emission characteristics as a function of experimental parameters in sharp field emitter devices. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 1995 , 13, 511		15
81	Secondary electron amplification using single-crystal CVD diamond film. <i>Diamond and Related Materials</i> , 2011 , 20, 798-802	3.5	14
80	Electron Emission Physics. Advances in Imaging and Electron Physics, 2007, 149, 1-46	0.2	14
79	Multiple scattering effects on quantum efficiency and response time for cesiated metal photocathodes. <i>Journal of Applied Physics</i> , 2011 , 110, 034504	2.5	13
78	Advanced emitters for next generation rf amplifiers. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 1998 , 16, 2038		13
77	Field emission from an elliptical boss: Exact and approximate forms for area factors and currents. Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena, 1994, 12, 776		13
76	Verifications of Schottky's Conjecture. <i>Journal of Applied Physics</i> , 2019 , 125, 215306	2.5	12
75	Investigation of the Schottky Conjecture for compound structures modeled with line charges. <i>Journal of Applied Physics</i> , 2019 , 125, 215307	2.5	12
74	Analytic model of electron transport through and over non-linear barriers. <i>Journal of Applied Physics</i> , 2020 , 127, 235301	2.5	12
73	Emittance of a photocathode: Effects of temperature and field. <i>Physical Review Special Topics:</i> Accelerators and Beams, 2010 , 13,		12
7 2	Space charge, emittance, trajectories, and the modeling of field emitter arrays. <i>Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics</i> , 2011 , 29, 02B101	1.3	12
71	Emission nonuniformity due to profilimetry variation in thermionic cathodes. <i>Applied Physics Letters</i> , 2006 , 88, 164105	3.4	12
70	Time dependent, self-consistent simulations of field emission from silicon using the Wigner distribution function. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 1994 , 12, 770		12
69	Modeling emission lag after photoexcitation. <i>Journal of Applied Physics</i> , 2017 , 122, 164501	2.5	11
68	. IEEE Transactions on Electron Devices, 2001 , 48, 614-627	2.9	11

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67	Analytic model of a compound thermal-field emitter and its performance. <i>Journal of Applied Physics</i> , 2019 , 126, 245301	2.5	11	
66	Free-Standing Bialkali Photocathodes Using Atomically Thin Substrates. <i>Advanced Materials Interfaces</i> , 2018 , 5, 1800249	4.6	10	
65	A photoemission moments model using density functional and transfer matrix methods applied to coating layers on surfaces: Theory. <i>Journal of Applied Physics</i> , 2018 , 123, 045301	2.5	10	
64	Analytical models of transmission probabilities for electron sources. <i>Journal of Applied Physics</i> , 2018 , 123, 065301	2.5	10	
63	Photoemission Theory and the Development of High Performance Photocathodes. <i>Journal of Computational and Theoretical Nanoscience</i> , 2009 , 6, 1754-1769	0.3	10	
62	Field-enhanced photoemission from metals and coated materials. <i>Journal of Vacuum Science & Technology B</i> , 2006 , 24, 863		10	
61	Simulation of time-dependent quantum transport in field emission from semiconductors: Complications due to scattering, surface density, and temperature. Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and		10	
60	Phenomena, 1995, 13, 505 Theoretical analysis of 1D resonant tunneling behavior in ion-enhanced cold field and thermo-field emission. <i>Journal of Applied Physics</i> , 2016, 120, 213301	2.5	9	
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58	Field emission from an elliptical boss: Exact versus approximate treatments. <i>Applied Physics Letters</i> , 1993 , 63, 702-704	3.4	8	
57	Spatial dependence of the temperature profile along a carbon nanotube during thermal-field emission. <i>Journal of Applied Physics</i> , 2020 , 128, 025107	2.5	8	
56	Delayed photo-emission model for beam optics codes. <i>Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics</i> , 2017 , 35, 02C102	1.3	7	
55	A, B, and C characterization of gated field emission arrays for radio frequency device performance. Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena, 1996 , 14, 1994		7	
54	Influence of image force potential on the shot noise properties of field emitters. <i>Applied Physics Letters</i> , 2004 , 85, 3763-3765	3.4	7	
53	Shot noise power spectrum of planar field emitters. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 2005 , 23, 380		7	
52	Semianalytical model of electron source potential barriers. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 1999 , 17, 515		7	
51	Design and construction of apparatus for characterization of gated field emitter array electron emission. <i>Review of Scientific Instruments</i> , 1996 , 67, 2387-2393	1.7	7	
50	A new multiscale approach to rapidly determine the local emission current density of nanoscale metallic field emitters. <i>Journal of Applied Physics</i> , 2021 , 130, 144302	2.5	7	

49	Electron emission from a single Spindt-type field emitter structure: Correlation of theory and experiment. <i>Applied Physics Letters</i> , 1996 , 68, 2807-2809	3.4	6
48	Semi-analytic model of a carbon fiber thermal-field emitter. <i>Journal of Applied Physics</i> , 2021 , 129, 0951	02 .5	6
47	Demonstration of 3-D-Printed Field-Emission Cathodes. <i>IEEE Transactions on Plasma Science</i> , 2019 , 47, 4292-4300	1.3	5
46	Analytic Wigner distribution function for tunneling and trajectory models. <i>Journal of Applied Physics</i> , 2019 , 125, 114303	2.5	5
45	Towards a Robust, Efficient Dispenser Photocathode: the Effect of Recesiation on Quantum Efficiency 2009 ,		5
44	Analytical and seminumerical models for gated field emitter arrays. II. Comparison of theory to experiment. <i>Journal of Vacuum Science & Technology an Official Journal of the American Vacuum Society B, Microelectronics Processing and Phenomena</i> , 1996 , 14, 1947		5
43	A comparison of flicker noise and shot noise on a hot cathode. <i>IEEE Transactions on Plasma Science</i> , 2000 , 28, 794-797	1.3	5
42	Enhancing secondary yield of a diamond amplifier using a nitrogen layer. <i>Journal of Applied Physics</i> , 2015 , 117, 214501	2.5	4
41	Electron Emission Physics. Advances in Imaging and Electron Physics, 2007, 280-323	0.2	4
40	ORIGIN OF HYSTERESIS AND PLATEAU-LIKE BEHAVIOR OF THE I-V CHARACTERISTICS OF RESONANT TUNNELING DIODES. <i>International Journal of Modern Physics B</i> , 2000 , 14, 411-426	1.1	4
39	Analytic expressions for emission in sharp field emitter diodes. <i>Journal of Applied Physics</i> , 1995 , 77, 350	692357	1 4
38	Wigner wave packets: Transmission, reflection, and tunneling. <i>Physical Review B</i> , 2021 , 103,	3.3	4
37	Quantum Efficiency Enhancement of Bialkali Photocathodes by an Atomically Thin Layer on Substrates. <i>Physica Status Solidi (A) Applications and Materials Science</i> , 2019 , 216, 1900501	1.6	3
36	Deposition and spin polarization study of Fe4N thin films with (111) orientation. <i>AIP Advances</i> , 2017 , 7, 095001	1.5	3
35	The Quantum Mechanical Extension of the Drude Zener Theory and the Optical Constants of an Alpha Semiconductor. <i>Journal of Computational and Theoretical Nanoscience</i> , 2009 , 6, 1770-1788	0.3	3
34	Advanced photocathode simulation and theory. <i>Nuclear Instruments and Methods in Physics Research, Section A: Accelerators, Spectrometers, Detectors and Associated Equipment</i> , 2003 , 507, 238-24	41 ^{1.2}	3
33	A COMPARISON OF THE TRANSMISSION COEFFICIENT AND THE WIGNER FUNCTION APPROACHES TO FIELD EMISSION. <i>COMPEL - the International Journal for Computation and Mathematics in Electrical and Electronic Engineering</i> , 1992 , 11, 457-470	0.7	3
32	Density of states of Cs3Sb calculated using density-functional theory for modeling photoemission 2017 ,		3

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31	An extended moments model of quantum efficiency for metals and semiconductors. <i>Journal of Applied Physics</i> , 2020 , 128, 015301	2.5	3
30	Reevaluating the Hartman effect for field emission. <i>Physical Review A</i> , 2021 , 104,	2.6	3
29	Analytic Wigner distribution function for a split potential well. <i>Journal of Applied Physics</i> , 2019 , 126, 144	13051	2
28	Electrostatic time-domain PIC simulations of RF density-modulated electron sources with MICHELLE 2012 ,		2
27	11.6: Emission characterization of diamond current amplifier 2010 ,		2
26	Modeling the quantum efficiency of controlled porosity dispenser photocathodes. <i>Applied Physics Letters</i> , 2012 , 100, 034102	3.4	2
25	Enhanced lifetime hybrid-diffuser cesium reservoir photocathode 2012 ,		2
24	MMW to upper-MMW vacuum electronics research at NRL 2009 ,		2
23	Electron Emission Physics. Advances in Imaging and Electron Physics, 2007, 149, 147-279	0.2	2
22	Emission statistics and the characterization of array current		2
21	QUANTUM TRANSPORT: NOVEL APPROACHES IN THE FORMULATION AND APPLICATIONS TO QUANTUM-BASED SOLID-STATE DEVICES. <i>COMPEL - the International Journal for Computation and Mathematics in Electrical and Electronic Engineering</i> , 1991 , 10, 509-524	0.7	2
20	Cesium-Coated Halide Perovskites as a Photocathode Material: Modeling Insights. <i>Journal of Physical Chemistry Letters</i> , 2021 , 12, 6269-6276	6.4	2
19	Photocathode: Free-Standing Bialkali Photocathodes Using Atomically Thin Substrates (Adv. Mater. Interfaces 13/2018). <i>Advanced Materials Interfaces</i> , 2018 , 5, 1870065	4.6	1
18	Modeling the resupply, diffusion, and evaporation of cesium on the surface of controlled porosity dispenser photocathodes. <i>Journal of Applied Physics</i> , 2013 , 114, 104906	2.5	1
17	11.3: Emittance, space charge, and sharp electron sources 2010 ,		1
16	A theoretical photocathode emittance model including temperature and field effects 2007,		1
15	Infrared photoelectron emission from Scandate dispenser cathodes. <i>Applied Physics Letters</i> , 2003 , 83, 1269-1271	3.4	1
14	Simulation of the Influence of Interface Charge on Electron Emission. <i>Materials Research Society Symposia Proceedings</i> , 2000 , 621, 331		1

13	Space Based Applications for FEA Cathodes (FEAC). <i>Materials Research Society Symposia Proceedings</i> , 2000 , 621, 481		1
12	Electron Transmission Through Modified Schottky Barriers. <i>Materials Research Society Symposia Proceedings</i> , 2001 , 685, 1		1
11	SIMULATION OF FIELD EMISSION FROM SILICON: SELF-CONSISTENT CORRECTIONS USING THE WIGNER DISTRIBUTION FUNCTION. <i>COMPEL - the International Journal for Computation and Mathematics in Electrical and Electronic Engineering</i> , 1993 , 12, 507-515	0.7	1
10	Thermal-field emission from cones and wires. <i>Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics</i> , 2022 , 40, 022801	1.3	1
9	Calculation of density of states for modeling photoemission using method of moments 2017,		1
8	A Thermal-Field-Photoemission Model and Its Application. <i>Topics in Applied Physics</i> , 2020 , 345-385	0.5	1
7	Secondary Electron Transmission Studies of the Electron Diffusion and Thermalization Processes in Thin CVD Diamond Films. <i>MRS Advances</i> , 2016 , 1, 1081-1086	0.7	0
6	Modeling the evaporation rate of cesium off tungsten based controlled porosity dispenser photocathodes. <i>AIP Advances</i> , 2013 , 3, 042105	1.5	
5	Fabrication and Characterization of Single-crystal CVD Diamond Current Amplifier. <i>Materials Research Society Symposia Proceedings</i> , 2011 , 1282, 129		
4	Theoretical Analysis of Fowler Nordheim Parameterization and RLC Characteristics for Ring Cathode Field Emitter Arrays for Next Generation RF Amplifiers. <i>Materials Research Society Symposia Proceedings</i> , 1998 , 509, 3		
3	Analysis of Measured I(V) Relations for Electron Emission from Insulating Diamond Films on Various SI Substrates. <i>Materials Research Society Symposia Proceedings</i> , 1999 , 558, 603		
2	The Inclusion of Scattering in the Simulation of Quantum Well Devices 1991 , 239-242		

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